



BC546/547/548

Description of TO-92 NPN Amplifier Transistor

- High Voltage: BC546,547,548 $V_{CE0}=65V, 45V, 30V$
- Power dissipation $P_{cm}: 0.625W(T_a=25C)$
- Collector current $I_{cm}: 0.1A$
- Collector-base voltage: $V(BR)CBO: BC546: 80V, BC547: 50V, BC548: 30V$
- Operating and storage junction temperature range: $T_J, T_{stg}: -55 \sim 150C$



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Value | Units |
|-----------|-----------------------------------|-----------|-------------|
| V_{CBO} | Collector-Base Voltage : BC546 | 80 | V |
| | $I_C=100\mu A, I_E=0$: BC547 | 50 | V |
| | : BC548 | 30 | V |
| V_{CE0} | Collector-Emitter Voltage : BC546 | 65 | V |
| | $I_C=1mA, I_B=0$: BC547 | 45 | V |
| | : BC548 | 30 | V |
| V_{EBO} | Emitter-Base Voltage : BC546/547 | 6 | V |
| | $I_E=10\mu A, I_C=0$: BC548 | 5 | V |
| I_C | Collector Current (DC) | 100 | mA |
| P_C | Collector Dissipation | 500 | mW |
| T_J | Junction Temperature | 150 | $^{\circ}C$ |
| T_{STG} | Storage Temperature | -55 ~ 150 | $^{\circ}C$ |

Electrical Characteristics $T_a=25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Typ. | Max. | Units |
|---------------|--------------------------------------|---------------------------------|-----------------------------------|------|------|-------|
| I_{CBO} | Collector Cut-off Current | $V_{CB}=30V, I_E=0$ | | | 15 | nA |
| h_{FE} | DC Current Gain | $V_{CE}=5V, I_C=2mA$ | 110 | | 800 | |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C=10mA, I_B=0.5mA$ | | 90 | 250 | mV |
| | | $I_C=100mA, I_B=5mA$ | | 200 | 600 | mV |
| $V_{BE(sat)}$ | Base-Emitter Saturation Voltage | $I_C=10mA, I_B=0.5mA$ | | 700 | | mV |
| | | $I_C=100mA, I_B=5mA$ | | | | mV |
| $V_{BE(on)}$ | Base-Emitter On Voltage | $V_{CE}=5V, I_C=2mA$ | 580 | 660 | 700 | mV |
| | | $V_{CE}=5V, I_C=10mA$ | | | 720 | mV |
| f_T | Current Gain Bandwidth Product | $V_{CE}=5V, I_C=10mA, f=100MHz$ | 150 | 300 | | MHz |
| C_{ob} | Output Capacitance | $V_{CB}=10V, I_E=0, f=1MHz$ | | 3.5 | 6 | pF |
| C_{ib} | Input Capacitance | $V_{EB}=0.5V, I_C=0, f=1MHz$ | | 9 | | pF |
| NF | Noise Figure | : BC546/547/548 | | 2 | 10 | dB |
| | | : BC549/550 | $f=1KHz, R_G=2K\Omega$ | 1.2 | 4 | dB |
| | | : BC549 | $V_{CE}=5V, I_C=200\mu A$ | 1.4 | 4 | dB |
| | | : BC550 | $R_G=2K\Omega, f=30\sim 15000MHz$ | 1.4 | 3 | dB |

h_{FE} Classification

| Classification | A | B | C |
|----------------|-----------|-----------|-----------|
| h_{FE} | 110 ~ 220 | 200 ~ 450 | 420 ~ 800 |

Typical Characteristics

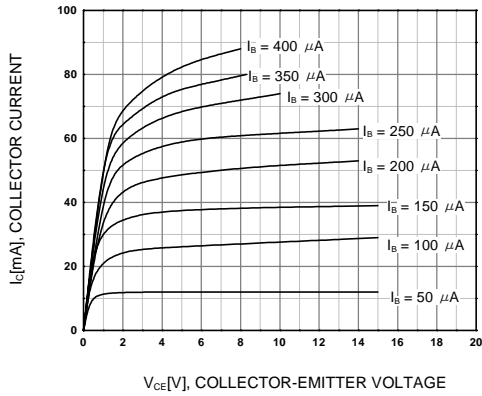


Figure 1. Static Characteristic

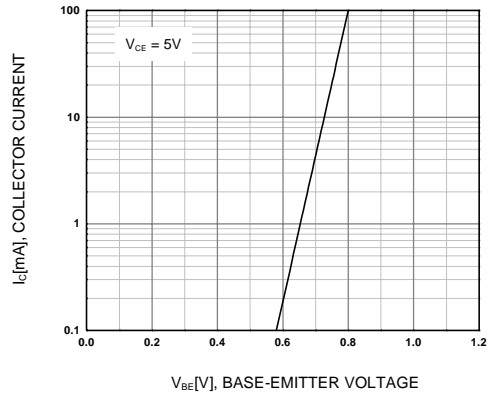


Figure 2. Transfer Characteristic

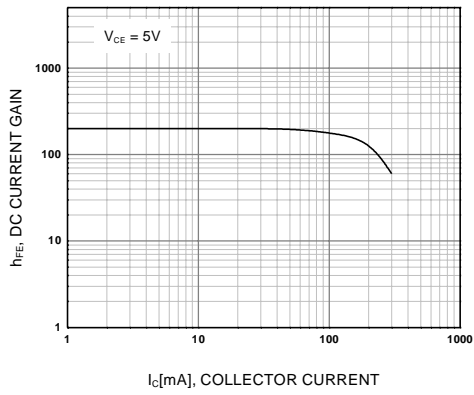


Figure 3. DC current Gain

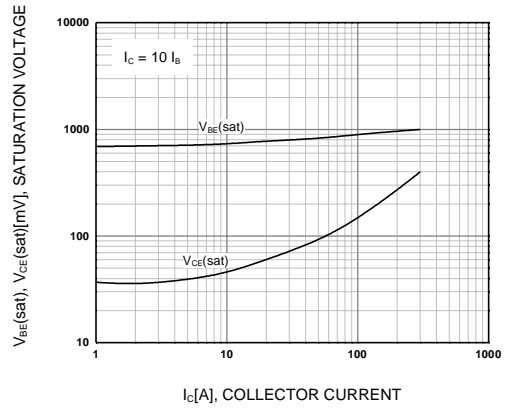


Figure 4. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

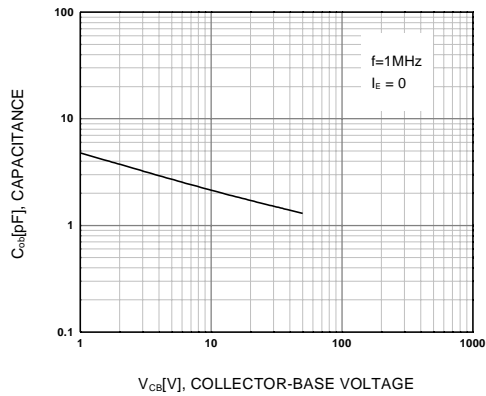


Figure 5. Output Capacitance

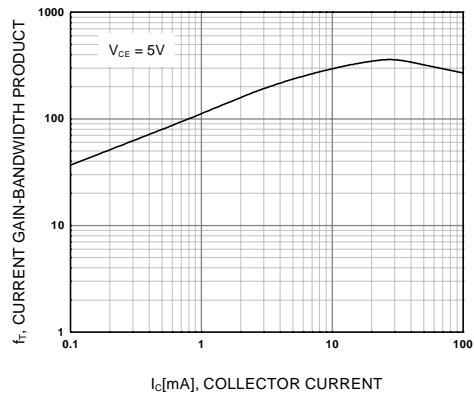


Figure 6. Current Gain Bandwidth Product